

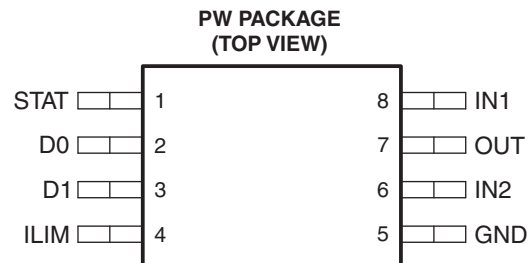
## AUTO-SWITCHING POWER MULTIPLEXER

### FEATURES

- Qualified for Automotive Applications
- Two-Input One-Output Power Multiplexer With Low  $r_{DS(on)}$  Switch...84 m $\Omega$  (Typ)
- Reverse and Cross-Conduction Blocking
- Wide Operating Voltage Range...2.8 V to 5.5 V
- Low Standby Current...0.5  $\mu$ A (Typ)
- Low Operating Current...55  $\mu$ A (Typ)
- Adjustable Current Limit
- Controlled Output Voltage Transition Times
- Limit Inrush Current and Minimize Output Voltage Hold-Up Capacitance
- CMOS- and TTL-Compatible Control Inputs
- Manual and Auto-Switching Operating Modes
- Thermal Shutdown
- Available in TSSOP-8 (PW) Package

### APPLICATIONS

- PCs
- PDAs
- Digital Cameras
- Modems
- Cell Phones
- Digital Radios
- MP3 Players



### DESCRIPTION/ORDERING INFORMATION

The TPS2115A power multiplexer enables seamless transition between two power supplies, such as a battery and a wall adapter, each operating at 2.8 V to 5.5 V and delivering up to 1 A. The TPS2115A includes extensive protection circuitry including user-programmable current limiting, thermal protection, inrush current control, seamless supply transition, cross-conduction blocking, and reverse-conduction blocking. These features greatly simplify designing power multiplexer applications.

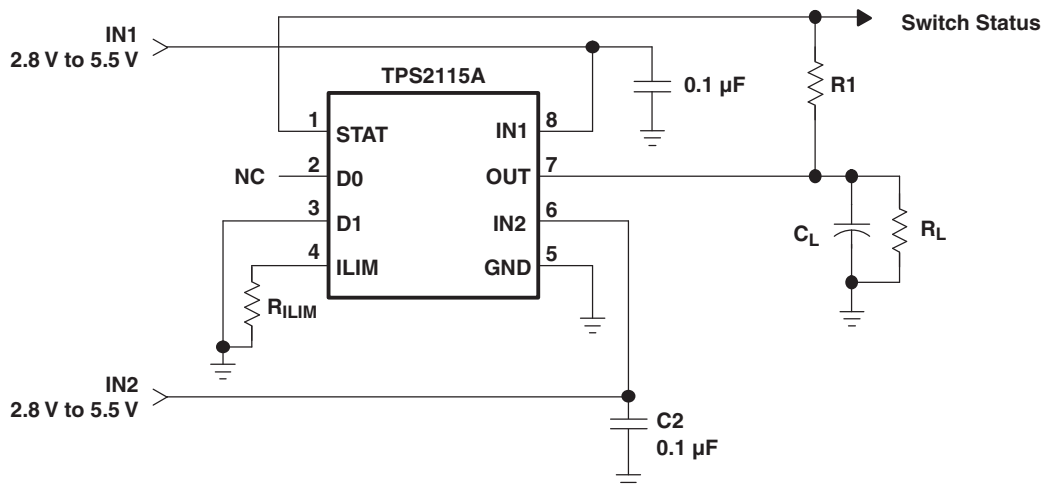


Figure 1. Typical Application



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

**ORDERING INFORMATION<sup>(1)</sup>**

| $T_A$         | PACKAGE <sup>(2)</sup> |              | ORDERABLE PART NUMBER | TOP-SIDE MARKING |
|---------------|------------------------|--------------|-----------------------|------------------|
| –40°C to 85°C | TSSOP – PW             | Reel of 2000 | TPS2115AIPWRQ1        | 2115AQ           |

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at [www.ti.com](http://www.ti.com).
- (2) Package drawings, thermal data, and symbolization are available at [www.ti.com/packaging](http://www.ti.com/packaging).

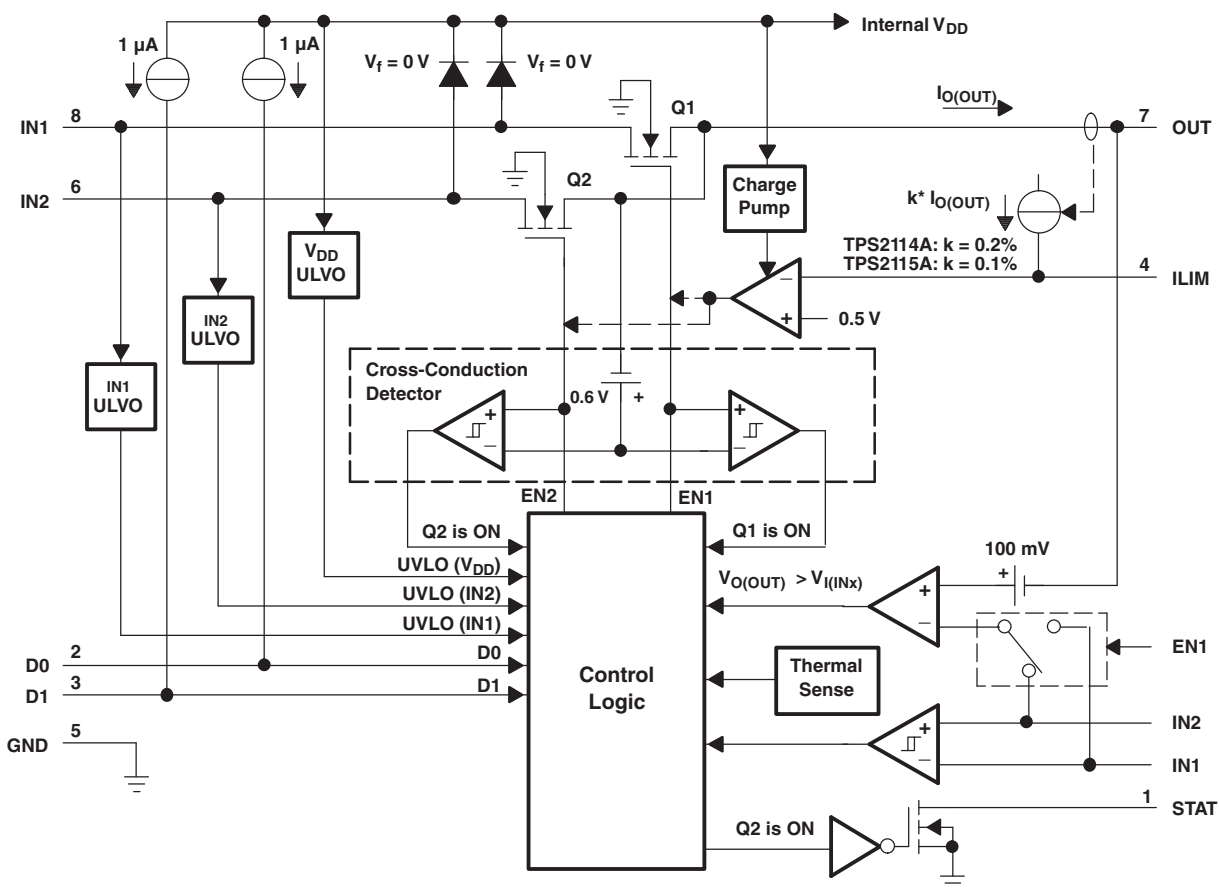
**TRUTH TABLE**

| D0 | D1 | $V_{I(IN2)} > V_{I(IN1)}$ <sup>(1)</sup> | STAT | OUT <sup>(2)</sup> |
|----|----|------------------------------------------|------|--------------------|
| 0  | 0  | X                                        | Hi-Z | IN2                |
| 0  | 1  | No                                       | 0    | IN1                |
| 0  | 1  | Yes                                      | Hi-Z | IN2                |
| 1  | 0  | X                                        | 0    | IN1                |
| 1  | 1  | X                                        | 0    | Hi-Z               |

- (1) X = don't care
- (2) The undervoltage lockout circuit causes the output OUT to go Hi-Z if the selected power supply does not exceed the IN1/IN2 UVLO, or if neither of the supplies exceeds the internal  $V_{DD}$  UVLO.

**TERMINAL FUNCTIONS**

| TERMINAL |     | I/O | DESCRIPTION                                                                                                                                                                |
|----------|-----|-----|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| NAME     | NO. |     |                                                                                                                                                                            |
| D0       | 2   | I   | TTL- and CMOS-compatible input pins. Each pin has a 1- $\mu$ A pullup. The <i>Truth Table</i> shows the functionality of D0 and D1.                                        |
| D1       | 3   | I   |                                                                                                                                                                            |
| GND      | 5   | I   | Ground                                                                                                                                                                     |
| IN1      | 8   | I   | Primary power switch input. The IN1 switch can be enabled only if the IN1 supply is above the UVLO threshold and at least one supply exceeds the internal $V_{DD}$ UVLO.   |
| IN2      | 6   | I   | Secondary power switch input. The IN2 switch can be enabled only if the IN2 supply is above the UVLO threshold and at least one supply exceeds the internal $V_{DD}$ UVLO. |
| ILIM     | 4   | I   | A resistor $R_{ILIM}$ from ILIM to GND sets the current limit $I_L$ to $500/R_{ILIM}$ .                                                                                    |
| OUT      | 7   | O   | Power switch output                                                                                                                                                        |
| STAT     | 1   | O   | Open-drain output that is Hi-Z if the IN2 switch is ON. STAT pulls low if the IN1 switch is ON or if OUT is Hi-Z (i.e., EN is equal to logic 0).                           |



**ABSOLUTE MAXIMUM RATINGS<sup>(1)(2)</sup>**

over operating free-air temperature range unless otherwise noted

|               |                                              |                                             |                                         |
|---------------|----------------------------------------------|---------------------------------------------|-----------------------------------------|
| $V_I$         | Input voltage range                          | IN1, IN2, D0, D1, ILIM                      | –0.3 V to 6 V                           |
| $V_O$         | Output voltage range                         | OUT, STAT                                   | –0.3 V to 6 V                           |
| $I_{O(sink)}$ | Output sink current                          | STAT                                        | 5 mA                                    |
| $I_O$         | Continuous output current                    |                                             | 1.5 mA                                  |
| $P_D$         | Continuous total power dissipation           |                                             | See <a href="#">Dissipation Ratings</a> |
| $T_A$         | Operating free-air temperature range         |                                             | –40°C to 85°C                           |
| $T_J$         | Operating virtual-junction temperature range |                                             | –40°C to 125°C                          |
| $T_{stg}$     | Storage temperature range                    |                                             | –65°C to 150°C                          |
| $T_{lead}$    | Lead temperature soldering                   | 1,6 mm (1/16 inch) from case for 10 seconds | 260°C                                   |

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltages are with respect to GND.

**ELECTROSTATIC DISCHARGE (ESD) PROTECTION**

|     |                                    | MAX                        | UNIT |
|-----|------------------------------------|----------------------------|------|
| ESD | Electrostatic discharge protection | Human-Body Model (HBM)     | 2000 |
|     |                                    | Charged-Device Model (CDM) | 500  |

**DISSIPATION RATINGS**

| PACKAGE    | DERATING FACTOR<br>ABOVE $T_A = 25^\circ\text{C}$ | $T_A \leq 25^\circ\text{C}$<br>POWER RATING | $T_A = 70^\circ\text{C}$<br>POWER RATING | $T_A = 85^\circ\text{C}$<br>POWER RATING |
|------------|---------------------------------------------------|---------------------------------------------|------------------------------------------|------------------------------------------|
| TSSOP (PW) | 3.9 mW/°C                                         | 387 mW                                      | 213 mW                                   | 155 mW                                   |

**RECOMMENDED OPERATING CONDITIONS**

|          |                                              |        | MIN                            | MAX  | UNIT |
|----------|----------------------------------------------|--------|--------------------------------|------|------|
| $V_I$    | Input voltage                                | IN1    | $V_{I(IN2)} \geq 2.8\text{ V}$ | 1.5  | 5.5  |
|          |                                              |        | $V_{I(IN2)} < 2.8\text{ V}$    | 2.8  | 5.5  |
|          |                                              | IN2    | $V_{I(IN1)} \geq 2.8\text{ V}$ | 1.5  | 5.5  |
|          |                                              |        | $V_{I(IN1)} < 2.8\text{ V}$    | 2.8  | 5.5  |
|          |                                              | D0, D1 | 0                              | 5.5  |      |
| $V_{IH}$ | High-level input voltage                     | D0, D1 | 2                              |      | V    |
| $V_{IL}$ | Low-level input voltage                      | D0, D1 |                                | 0.7  | V    |
| $I_O$    | Current limit adjustment range               | OUT    | 0.63                           | 1.25 | A    |
| $T_A$    | Operating free-air temperature               |        | –40                            | 85   | °C   |
| $T_J$    | Operating virtual-junction temperature range |        | –40                            | 125  | °C   |

## ELECTRICAL CHARACTERISTICS

over operating free-air temperature range,  $V_{I(IN1)} = V_{I(IN2)} = 5.5 \text{ V}$ ,  $R_{ILIM} = 400 \Omega$  (unless otherwise noted)

| PARAMETER                                                                             |                                                                                                                                                                                       | TEST CONDITIONS                                           | MIN  | TYP  | MAX  | UNIT |
|---------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------------------------------------------|------|------|------|------|
| Power Switch <sup>(1)</sup>                                                           |                                                                                                                                                                                       |                                                           |      |      |      |      |
| $r_{DS(on)}$<br>Drain-source on-state resistance (INx to OUT)                         | $T_A = 25^{\circ}\text{C}$ , $I_L = 500\text{ mA}$                                                                                                                                    | $V_{I(IN1)} = V_{I(IN2)} = 5.0\text{ V}$                  |      | 84   | 110  | mΩ   |
|                                                                                       |                                                                                                                                                                                       | $V_{I(IN1)} = V_{I(IN2)} = 3.3\text{ V}$                  |      | 84   | 110  |      |
|                                                                                       |                                                                                                                                                                                       | $V_{I(IN1)} = V_{I(IN2)} = 2.8\text{ V}$                  |      | 84   | 110  |      |
|                                                                                       | $T_A = 85^{\circ}\text{C}$ , $I_L = 500\text{ mA}$                                                                                                                                    | $V_{I(IN1)} = V_{I(IN2)} = 5.0\text{ V}$                  |      |      | 150  |      |
|                                                                                       |                                                                                                                                                                                       | $V_{I(IN1)} = V_{I(IN2)} = 3.3\text{ V}$                  |      |      | 150  |      |
|                                                                                       |                                                                                                                                                                                       | $V_{I(IN1)} = V_{I(IN2)} = 2.8\text{ V}$                  |      |      | 150  |      |
| Logic Inputs (D0 and D1)                                                              |                                                                                                                                                                                       |                                                           |      |      |      |      |
| $I_i$<br>Input current at D0 or D1                                                    | D0 or D1 = high, sink current                                                                                                                                                         |                                                           |      |      | 1    | μA   |
|                                                                                       | D0 or D1 = low, source current                                                                                                                                                        |                                                           | 0.5  | 1.4  | 5    |      |
| Supply and Leakage Currents                                                           |                                                                                                                                                                                       |                                                           |      |      |      |      |
| Supply current from IN1 (operating)                                                   | D1 = high, D0 = low (IN1 active), $V_{I(IN1)} = 5.5\text{ V}$ , $V_{I(IN2)} = 3.3\text{ V}$ , $I_{O(OUT)} = 0\text{ A}$                                                               |                                                           |      | 55   | 90   | μA   |
|                                                                                       | D1 = high, D0 = low (IN1 active), $V_{I(IN1)} = 3.3\text{ V}$ , $V_{I(IN2)} = 5.5\text{ V}$ , $I_{O(OUT)} = 0\text{ A}$                                                               |                                                           |      | 1    | 12   |      |
|                                                                                       | D0 = D1 = low (IN2 active), $V_{I(IN1)} = 5.5\text{ V}$ , $V_{I(IN2)} = 3.3\text{ V}$ , $I_{O(OUT)} = 0\text{ A}$                                                                     |                                                           |      |      | 75   |      |
|                                                                                       | D0 = D1 = low (IN2 active), $V_{I(IN1)} = 3.3\text{ V}$ , $V_{I(IN2)} = 5.5\text{ V}$ , $I_{O(OUT)} = 0\text{ A}$                                                                     |                                                           |      |      | 1    |      |
| Supply current from IN2 (operating)                                                   | D1 = high, D0 = low (IN1 active), $V_{I(IN1)} = 5.5\text{ V}$ , $V_{I(IN2)} = 3.3\text{ V}$ , $I_{O(OUT)} = 0\text{ A}$                                                               |                                                           |      |      | 1    | μA   |
|                                                                                       | D1 = high, D0 = low (IN1 active), $V_{I(IN1)} = 3.3\text{ V}$ , $V_{I(IN2)} = 5.5\text{ V}$ , $I_{O(OUT)} = 0\text{ A}$                                                               |                                                           |      |      | 75   |      |
|                                                                                       | D0 = D1 = low (IN2 active), $V_{I(IN1)} = 5.5\text{ V}$ , $V_{I(IN2)} = 3.3\text{ V}$ , $I_{O(OUT)} = 0\text{ A}$                                                                     |                                                           |      | 1    | 12   |      |
|                                                                                       | D0 = D1 = low (IN2 active), $V_{I(IN1)} = 3.3\text{ V}$ , $V_{I(IN2)} = 5.5\text{ V}$ , $I_{O(OUT)} = 0\text{ A}$                                                                     |                                                           |      | 55   | 90   |      |
| Quiescent current from IN1 (standby)                                                  | D0 = D1 = high (inactive), $I_{O(OUT)} = 0\text{ A}$                                                                                                                                  | $V_{I(IN1)} = 5.5\text{ V}$ , $V_{I(IN2)} = 3.3\text{ V}$ |      | 0.5  | 2    | μA   |
|                                                                                       |                                                                                                                                                                                       | $V_{I(IN1)} = 3.3\text{ V}$ , $V_{I(IN2)} = 5.5\text{ V}$ |      |      | 1    |      |
| Quiescent current from IN2 (standby)                                                  | D0 = D1 = high (inactive), $I_{O(OUT)} = 0\text{ A}$                                                                                                                                  | $V_{I(IN1)} = 5.5\text{ V}$ , $V_{I(IN2)} = 3.3\text{ V}$ |      |      | 1    | μA   |
|                                                                                       |                                                                                                                                                                                       | $V_{I(IN1)} = 3.3\text{ V}$ , $V_{I(IN2)} = 5.5\text{ V}$ |      | 0.5  | 2    |      |
| Forward leakage current from IN1 (measured from OUT to GND)                           | D0 = D1 = high (inactive), $V_{I(IN1)} = 5.5\text{ V}$ , IN2 open, $V_{O(OUT)} = 0\text{ V}$ (shorted), $T_A = 25^{\circ}\text{C}$                                                    |                                                           |      | 0.1  | 5    | μA   |
| Forward leakage current from IN2 (measured from OUT to GND)                           | D0 = D1= high (inactive), $V_{I(IN2)} = 5.5\text{ V}$ , IN1 open, $V_{O(OUT)} = 0\text{ V}$ (shorted), $T_A = 25^{\circ}\text{C}$                                                     |                                                           |      | 0.1  | 5    | μA   |
| Reverse leakage current to INx (measured from INx to GND)                             | D0 = D1 = high (inactive), $V_{I(INx)} = 0\text{ V}$ , $V_{O(OUT)} = 5.5\text{ V}$ , $T_A = 25^{\circ}\text{C}$                                                                       |                                                           |      | 0.3  | 5    | μA   |
| Current Limit Circuit                                                                 |                                                                                                                                                                                       |                                                           |      |      |      |      |
| Current limit accuracy                                                                | $R_{ILIM} = 400\text{ }\Omega$                                                                                                                                                        |                                                           | 0.95 | 1.25 | 1.56 | A    |
|                                                                                       | $R_{ILIM} = 700\text{ }\Omega$                                                                                                                                                        |                                                           | 0.47 | 0.71 | 0.99 |      |
| $t_d$<br>Current limit settling time                                                  | Time for short-circuit output current to settle within 10% of its steady state value                                                                                                  |                                                           |      | 1    |      | ms   |
| $I_i$<br>Input current at ILIM                                                        | $V_{I(ILIM)} = 0\text{ V}$ , $I_{O(OUT)} = 0\text{ A}$                                                                                                                                |                                                           | −15  |      | 0    | μA   |
| UVLO                                                                                  |                                                                                                                                                                                       |                                                           |      |      |      |      |
| IN1 and IN2 UVLO                                                                      | Falling edge                                                                                                                                                                          |                                                           | 1.15 | 1.25 |      | V    |
|                                                                                       | Rising edge                                                                                                                                                                           |                                                           |      | 1.30 | 1.35 |      |
| IN1 and IN2 UVLO hysteresis                                                           |                                                                                                                                                                                       |                                                           | 30   | 57   | 65   | mV   |
| Internal VDD UVLO (the higher of IN1 and IN2)                                         | Falling edge                                                                                                                                                                          |                                                           | 2.4  | 2.53 |      | V    |
|                                                                                       | Rising edge                                                                                                                                                                           |                                                           |      | 2.58 | 2.8  |      |
| Internal VDD UVLO hysteresis                                                          |                                                                                                                                                                                       |                                                           | 30   | 50   | 75   | mV   |
| UVLO deglitch for IN1, IN2                                                            | Falling edge                                                                                                                                                                          |                                                           |      | 110  |      | μs   |
| Reverse Conduction Blocking                                                           |                                                                                                                                                                                       |                                                           |      |      |      |      |
| $\Delta V_{IO(blk)}$<br>Minimum input-to-output voltage difference to block switching | D0 = D1 = high, $V_{I(INx)} = 3.3\text{ V}$ . Connect OUT to a 5-V supply through a series 1-kΩ resistor. Set D0 = low. Slowly decrease the supply voltage until OUT connects to IN1. |                                                           | 80   | 100  | 120  | mV   |

- (1) The TPS2115A can switch a voltage as low as 1.5 V as long as there is a minimum of 2.8 V at one of the input power pins. In this specific case, the lower supply voltage has no effect on the IN1 and IN2 switch on-resistances.

**ELECTRICAL CHARACTERISTICS (continued)**

over operating free-air temperature range,  $V_{I(IN1)} = V_{I(IN2)} = 5.5\text{ V}$ ,  $R_{ILIM} = 400\ \Omega$  (unless otherwise noted)

| PARAMETER                                                    |                                    | TEST CONDITIONS                                | MIN | TYP  | MAX | UNIT          |
|--------------------------------------------------------------|------------------------------------|------------------------------------------------|-----|------|-----|---------------|
| <b>Thermal Shutdown</b>                                      |                                    |                                                |     |      |     |               |
| Thermal shutdown threshold                                   |                                    | TPS2115A is in current limit.                  | 135 |      |     | °C            |
| Recovery from thermal shutdown                               |                                    | TPS2115A is in current limit.                  | 125 |      |     | °C            |
| Hysteresis                                                   |                                    |                                                |     | 10   |     | °C            |
| <b>IN2-IN1 Comparators</b>                                   |                                    |                                                |     |      |     |               |
| Hysteresis of IN2-IN1 comparator                             |                                    |                                                | 0.1 |      | 0.2 | V             |
| Deglintch of IN2-IN1 comparator (both $\uparrow\downarrow$ ) |                                    |                                                | 10  | 20   | 50  | $\mu\text{s}$ |
| <b>STAT Output</b>                                           |                                    |                                                |     |      |     |               |
| $I_{leak}$                                                   | Leakage current                    | $V_{O(STAT)} = 5.5\text{ V}$                   |     | 0.01 | 1   | $\mu\text{A}$ |
| $V_{sat}$                                                    | Saturation voltage                 | $I_{I(STAT)} = 2\text{ mA}$ , IN1 switch is on |     | 0.13 | 0.4 | V             |
| $t_d$                                                        | Deglintch time (falling edge only) |                                                |     | 150  |     | $\mu\text{s}$ |

**SWITCHING CHARACTERISTICS**

over operating free-air temperature range,  $V_{I(IN1)} = V_{I(IN2)} = 5.5\text{ V}$ ,  $R_{ILIM} = 400\ \Omega$  (unless otherwise noted)

| PARAMETER           |                                           | TEST CONDITIONS                                                                                                                                                                                                                                                                            | MIN | TYP | MAX | UNIT          |
|---------------------|-------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----|-----|-----|---------------|
| <b>Power Switch</b> |                                           |                                                                                                                                                                                                                                                                                            |     |     |     |               |
| $t_r$               | Output rise time from an enable           | $V_{I(IN1)} = V_{I(IN2)} = 5\text{ V}$<br>$T_A = 25^\circ\text{C}$ , $C_L = 1\ \mu\text{F}$ , $I_L = 500\text{ mA}$ ,<br>See <a href="#">Figure 2(a)</a>                                                                                                                                   | 1   | 1.8 | 3   | ms            |
| $t_f$               | Output fall time from a disable           | $V_{I(IN1)} = V_{I(IN2)} = 5\text{ V}$<br>$T_A = 25^\circ\text{C}$ , $C_L = 1\ \mu\text{F}$ , $I_L = 500\text{ mA}$ ,<br>See <a href="#">Figure 2(a)</a>                                                                                                                                   | 0.5 | 1   | 2   | ms            |
| $t_t$               | Transition time                           | IN1 to IN2 transition, $V_{I(IN1)} = 3.3\text{ V}$ ,<br>$V_{I(IN2)} = 5\text{ V}$                                                                                                                                                                                                          |     | 40  | 60  | $\mu\text{s}$ |
|                     |                                           | IN2 to IN1 transition, $V_{I(IN1)} = 5\text{ V}$ ,<br>$V_{I(IN2)} = 3.3\text{ V}$                                                                                                                                                                                                          |     | 40  | 60  |               |
| $t_{PLH1}$          | Turn-on propagation delay from enable     | $V_{I(IN1)} = V_{I(IN2)} = 5\text{ V}$ , Measured from enable to 10% of $V_{O(OUT)}$<br>$T_A = 25^\circ\text{C}$ , $C_L = 10\ \mu\text{F}$ , $I_L = 500\text{ mA}$ ,<br>See <a href="#">Figure 2(a)</a>                                                                                    |     | 1   |     | ms            |
| $t_{PHL1}$          | Turn-off propagation delay from a disable | $V_{I(IN1)} = V_{I(IN2)} = 5\text{ V}$ , Measured from disable to 90% of $V_{O(OUT)}$<br>$T_A = 25^\circ\text{C}$ , $C_L = 10\ \mu\text{F}$ , $I_L = 500\text{ mA}$ ,<br>See <a href="#">Figure 2(a)</a>                                                                                   |     | 5   |     | ms            |
| $t_{PLH2}$          | Switch-over rising propagation delay      | Logic 1 to Logic 0 transition on D1,<br>$V_{I(IN1)} = 1.5\text{ V}$ , $V_{I(IN2)} = 5\text{ V}$ , $V_{I(D0)} = 0\text{ V}$ ,<br>Measured from D1 to 10% of $V_{O(OUT)}$<br>$T_A = 25^\circ\text{C}$ , $C_L = 10\ \mu\text{F}$ , $I_L = 500\text{ mA}$ ,<br>See <a href="#">Figure 2(c)</a> |     | 40  | 100 | $\mu\text{s}$ |
| $t_{PHL2}$          | Switch-over falling propagation delay     | Logic 0 to Logic 1 transition on D1,<br>$V_{I(IN1)} = 1.5\text{ V}$ , $V_{I(IN2)} = 5\text{ V}$ , $V_{I(D0)} = 0\text{ V}$ ,<br>Measured from D1 to 90% of $V_{O(OUT)}$<br>$T_A = 25^\circ\text{C}$ , $C_L = 10\ \mu\text{F}$ , $I_L = 500\text{ mA}$ ,<br>See <a href="#">Figure 2(c)</a> | 2   | 5   | 10  | ms            |

## PARAMETER MEASUREMENT INFORMATION

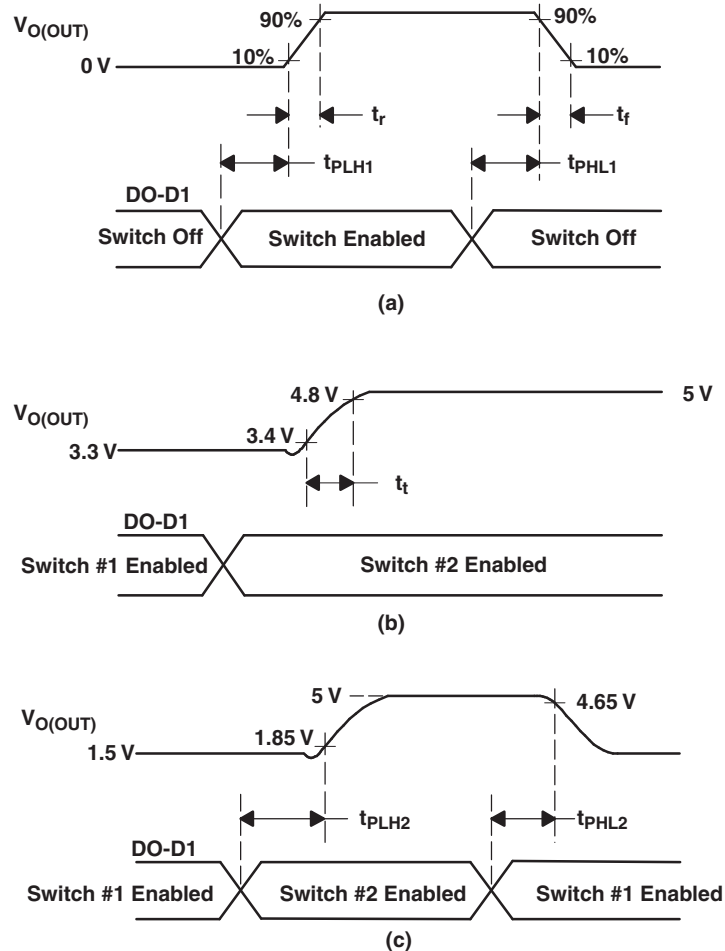
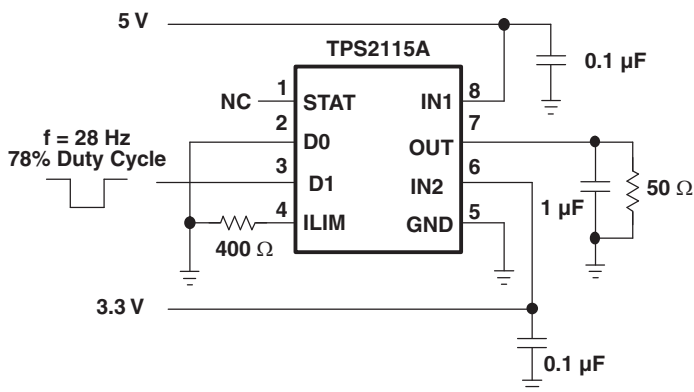
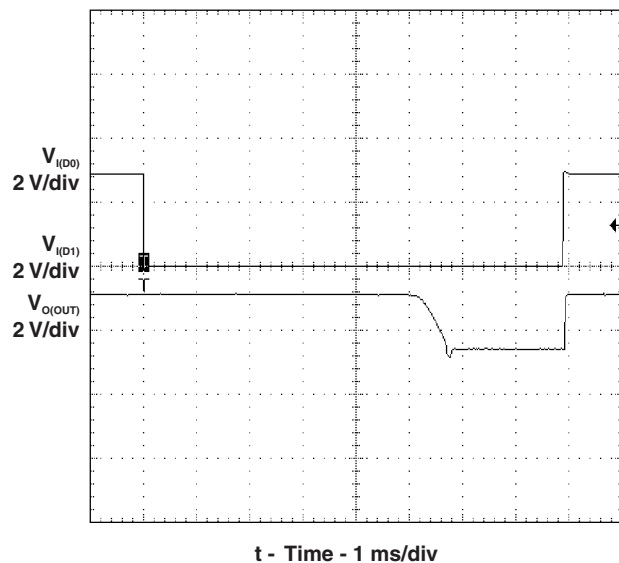


Figure 2. Propagation Delays and Transition Timing Waveforms

## TYPICAL CHARACTERISTICS

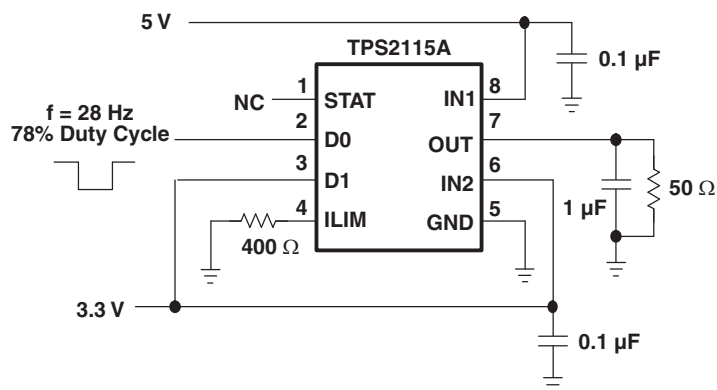
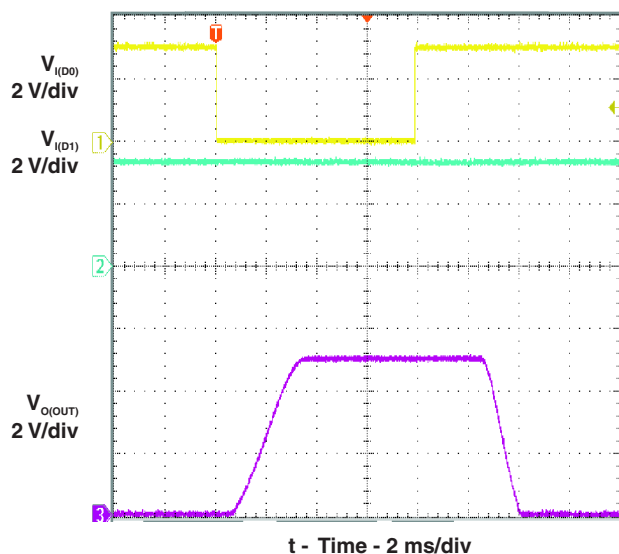
### OUTPUT SWITCHOVER RESPONSE



**Output Switchover Response Test Circuit**

Figure 3.

### OUTPUT TURN-ON RESPONSE

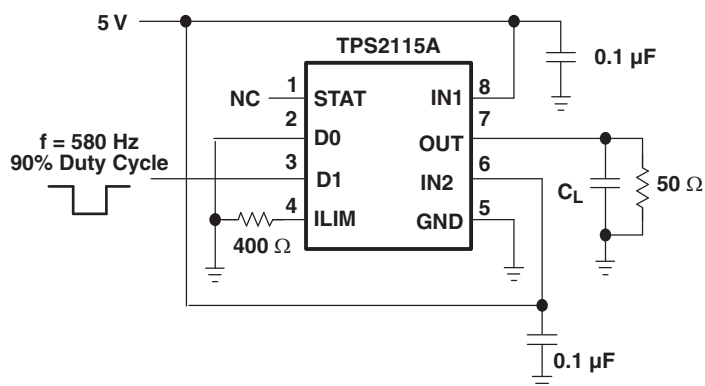
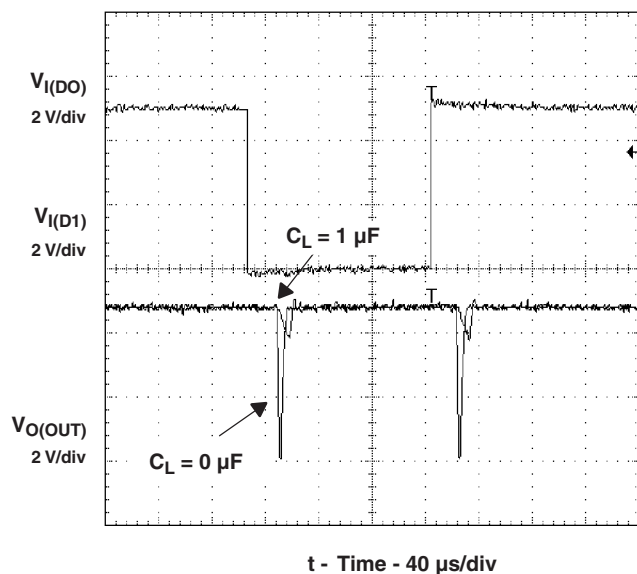


**Output Turn-On Response Test Circuit**

Figure 4.

# TYPICAL CHARACTERISTICS (continued)

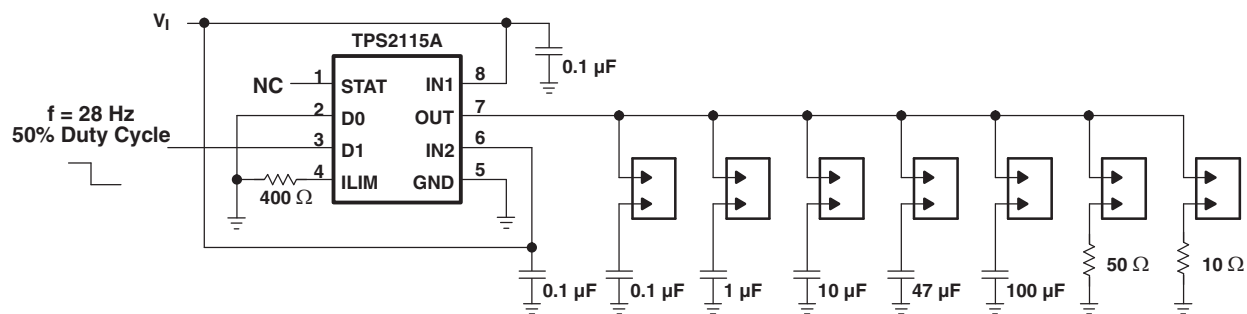
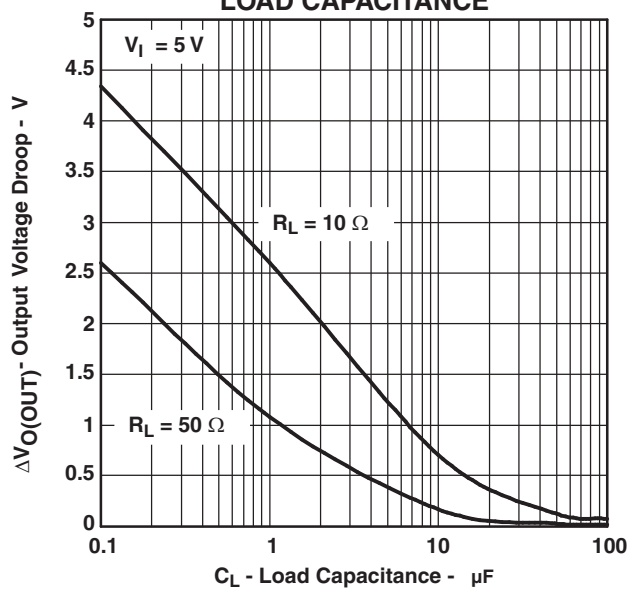
## OUTPUT SWITCHOVER VOLTAGE DROOP



Output Switchover Voltage Droop Test Circuit

Figure 5.

**TYPICAL CHARACTERISTICS (continued)**  
**OUTPUT SWITCHOVER VOLTAGE DROOP**  
**vs**  
**LOAD CAPACITANCE**

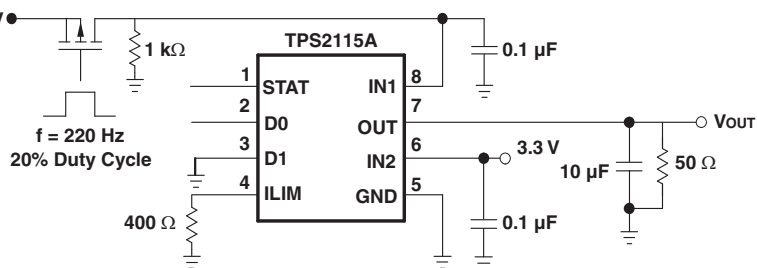
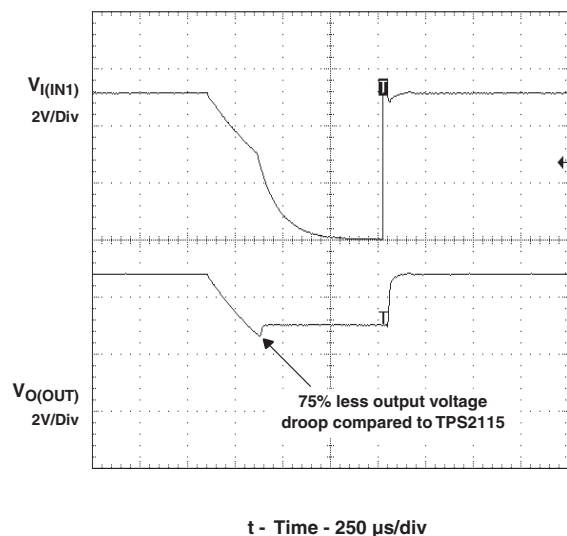


**Output Switchover Voltage Droop Test Circuit**

Figure 6.

## TYPICAL CHARACTERISTICS (continued)

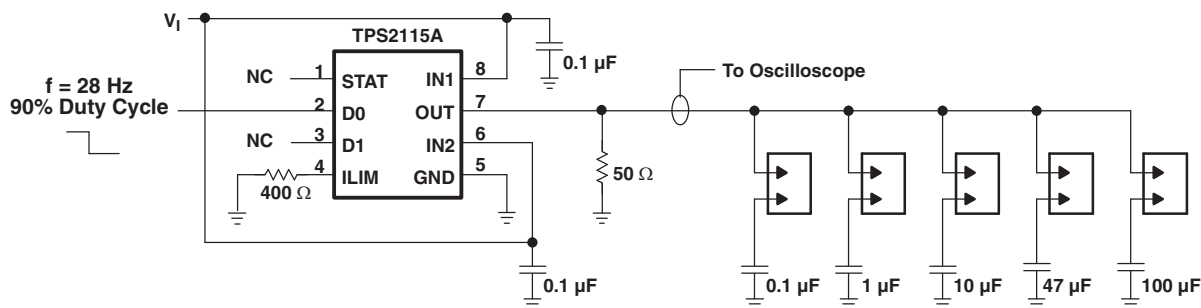
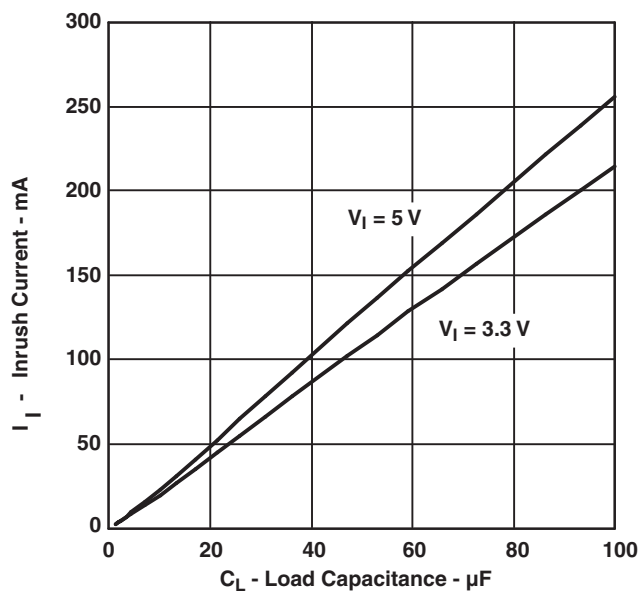
### AUTO SWITCHOVER VOLTAGE DROOP



Auto Switchover Voltage Droop Test Circuit

Figure 7.

**TYPICAL CHARACTERISTICS (continued)**  
**INRUSH CURRENT**  
**vs**  
**LOAD CAPACITANCE**



**Output Capacitor Inrush Current Test Circuit**  
 Figure 8.

# TYPICAL CHARACTERISTICS (continued)

SWITCH ON-RESISTANCE  
vs  
JUNCTION TEMPERATURE

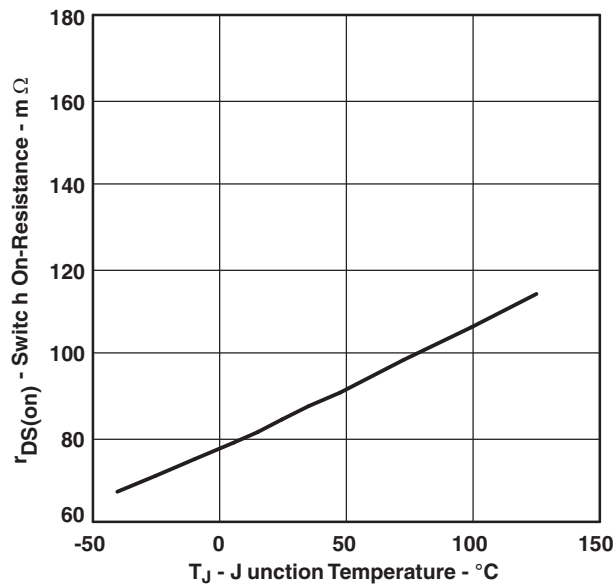


Figure 9.

SWITCH ON-RESISTANCE  
vs  
SUPPLY VOLTAGE

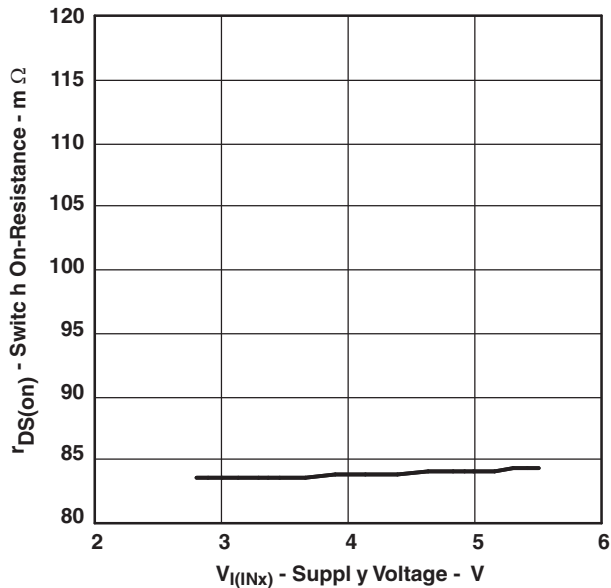


Figure 10.

IN1 SUPPLY CURRENT  
vs  
SUPPLY VOLTAGE

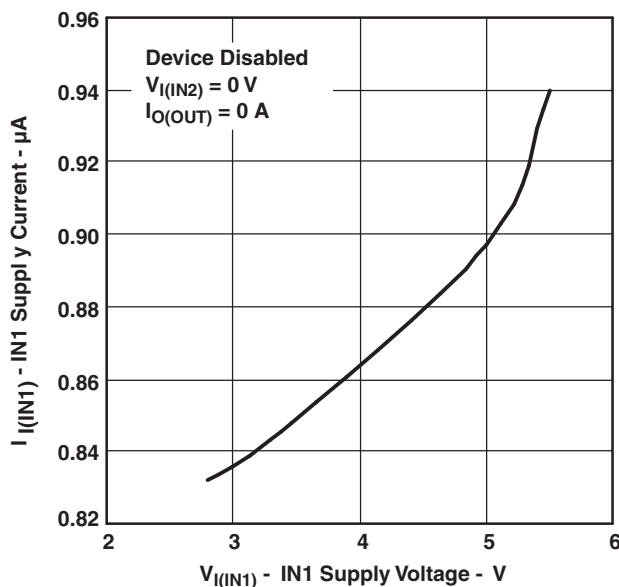


Figure 11.

IN1 SUPPLY CURRENT  
vs  
SUPPLY VOLTAGE

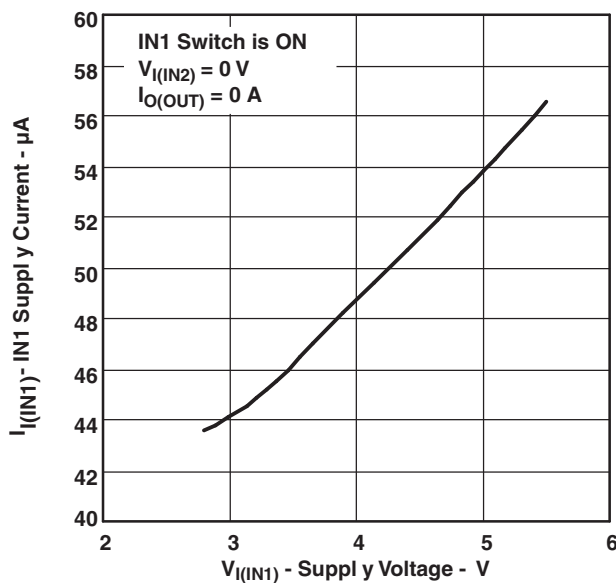
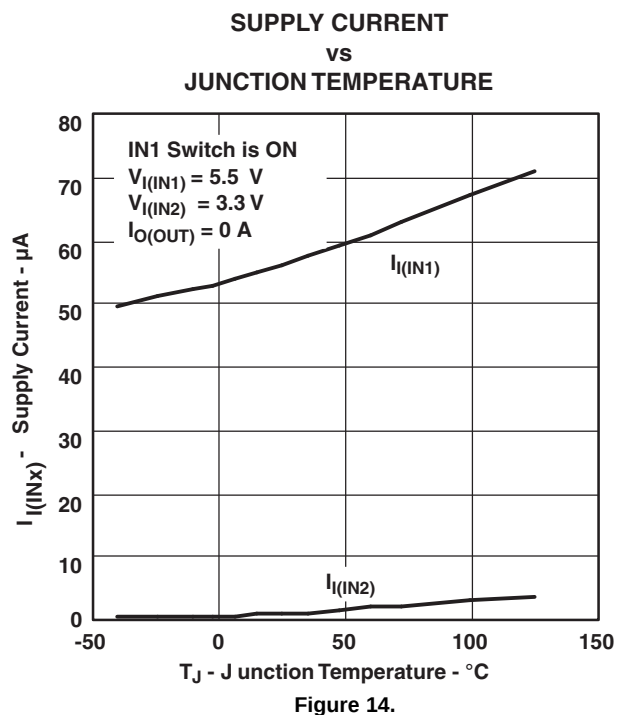
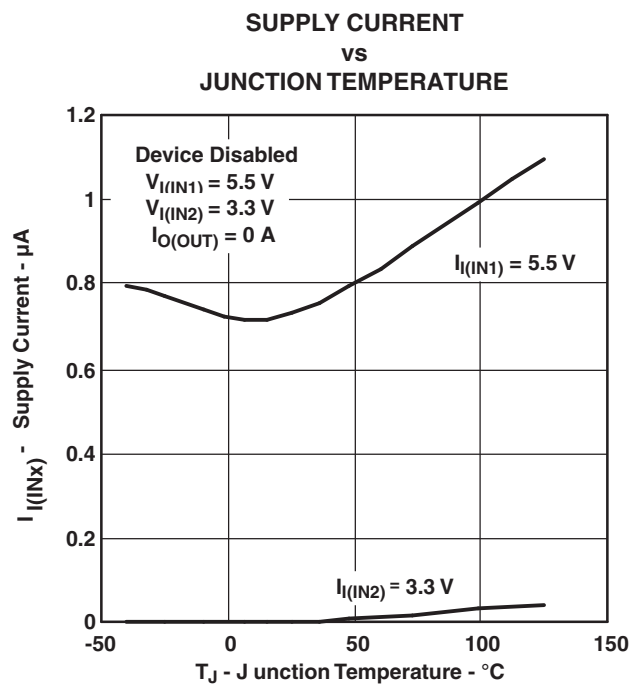


Figure 12.

## TYPICAL CHARACTERISTICS (continued)



## APPLICATION INFORMATION

Some applications have two energy sources, one of which should be used in preference to another. [Figure 15](#) shows a circuit that will connect IN1 to OUT until the voltage at IN1 falls below a user-specified value. Once the voltage on IN1 falls below this value, the TPS2115A will select the higher of the two supplies. This usually means that the TPS2115A will swap to IN2.

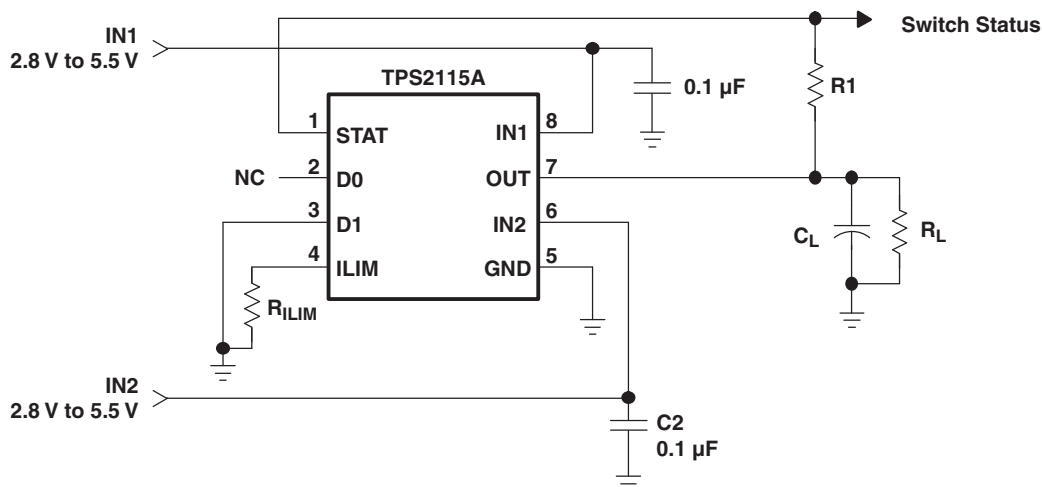


Figure 15. Auto-Selecting for a Dual Power Supply Application

In [Figure 16](#), the multiplexer selects between two power supplies based upon the D1 logic signal. OUT connects to IN1 if D1 is logic 1; otherwise, OUT connects to IN2. The logic thresholds for the D1 terminal are compatible with both TTL and CMOS logic.

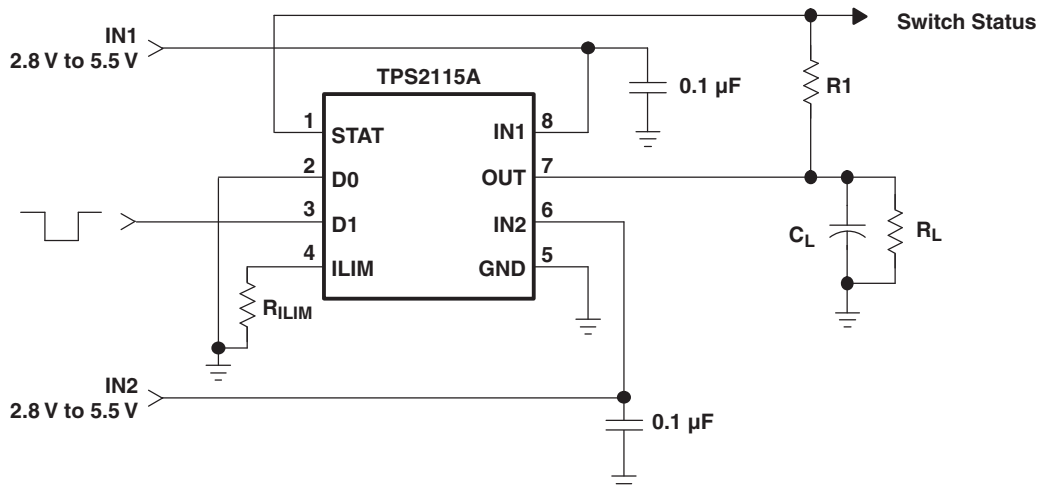


Figure 16. Manually Switching Power Sources

## DETAILED DESCRIPTION

### Auto-Switching Mode

D0 equal to logic 1 and D1 equal to logic 0 selects the auto-switching mode. In this mode, OUT connects to the higher of IN1 and IN2.

### Manual Switching Mode

D0 equal to logic 0 selects the manual-switching mode. In this mode, OUT connects to IN1 if D1 is equal to logic 1, otherwise OUT connects to IN2.

### N-Channel MOSFETs

Two internal high-side power MOSFETs implement a single-pole double-throw (SPDT) switch. Digital logic selects the IN1 switch, IN2 switch, or no switch (Hi-Z state). The MOSFETs have no parallel diodes so output-to-input current cannot flow when the FET is off. An integrated comparator prevents turn-on of a FET switch if the output voltage is greater than the input voltage.

### Cross-Conduction Blocking

The switching circuitry ensures that both power switches will never conduct at the same time. A comparator monitors the gate-to-source voltage of each power FET and allows a FET to turn on only if the gate-to-source voltage of the other FET is below the turn-on threshold voltage.

### Reverse-Conduction Blocking

When the TPS2115A switches from a higher-voltage supply to a lower-voltage supply, current can potentially flow back from the load capacitor into the lower-voltage supply. To minimize such reverse conduction, the TPS2115A will not connect a supply to the output until the output voltage has fallen to within 100 mV of the supply voltage. Once a supply has been connected to the output, it will remain connected regardless of output voltage.

### Charge Pump

The higher of supplies IN1 and IN2 powers the internal charge pump. The charge pump provides power to the current limit amplifier and allows the output FET gate voltage to be higher than the IN1 and IN2 supply voltages. A gate voltage that is higher than the source voltage is necessary to turn on the N-channel FET.

### Current Limiting

A resistor  $R_{ILIM}$  from ILIM to GND sets the current limit to  $500/R_{ILIM}$ . Setting resistor  $R_{ILIM}$  equal to zero is not recommended as that disables current limiting.

### Output Voltage Slew-Rate Control

The TPS2115A slews the output voltage at a slow rate when OUT switches to IN1 or IN2 from the Hi-Z state (see *Truth Table*). A slow slew rate limits the inrush current into the load capacitor. High inrush currents can glitch the voltage bus and cause a system to hang up or reset. It can also cause reliability issues such as pitting the connector power contacts when hot-plugging a load such as a PCI card. The TPS2115A slews the output voltage at a much faster rate when OUT switches between IN1 and IN2. The fast rate minimizes the output voltage droop and reduces the output voltage hold-up capacitance requirement.

## PACKAGING INFORMATION

| Orderable Device | Status<br>(1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan<br>(2)            | Lead/Ball Finish | MSL Peak Temp<br>(3) | Op Temp (°C) | Top-Side Markings<br>(4) | Samples                 |
|------------------|---------------|--------------|--------------------|------|----------------|----------------------------|------------------|----------------------|--------------|--------------------------|-------------------------|
| TPS2115AIPWRQ1   | ACTIVE        | TSSOP        | PW                 | 8    | 2000           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-3-260C-168 HR  | -40 to 85    | 2115AQ                   | <a href="#">Samples</a> |

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBsolete:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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### OTHER QUALIFIED VERSIONS OF TPS2115A-Q1 :

- Catalog: [TPS2115A](#)

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NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

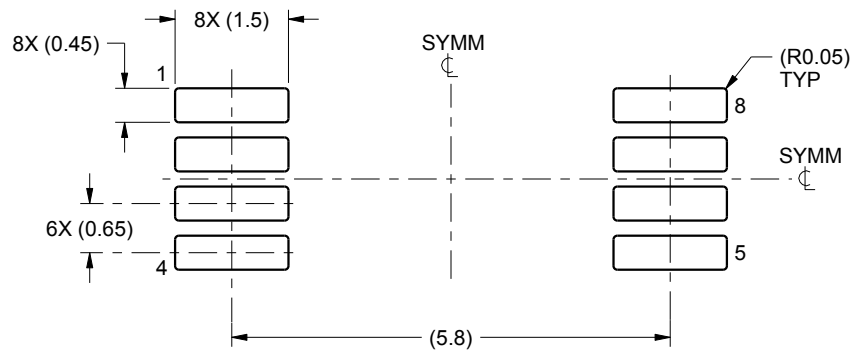


# EXAMPLE BOARD LAYOUT

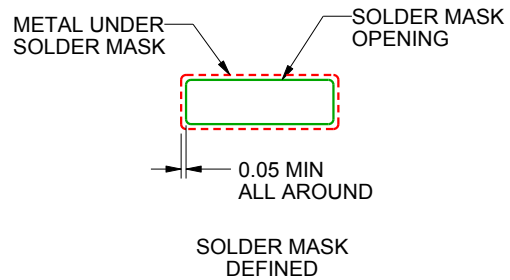
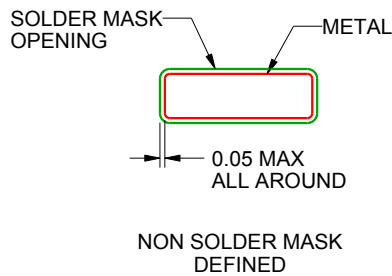
PW0008A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
SCALE:10X



SOLDER MASK DETAILS  
NOT TO SCALE

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NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

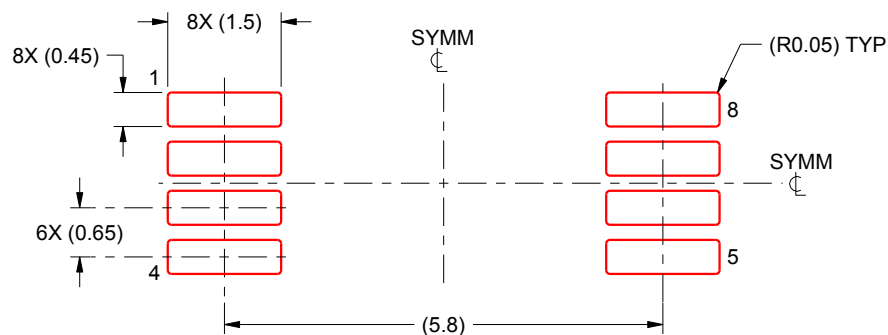
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

## EXAMPLE STENCIL DESIGN

PW0008A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:10X

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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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